NSN 5962-01-141-8099

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-141-8099

Body Length: 0.896 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** Between 0.140 inches and 0.185 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Countermeasures set type an/alq-99 e/i fscm 06129 **Features Provided:** Hermetically sealed and monolithic and positive outputs and low power and schottky and 3-state output **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern: Terminal Surface Treatment:** Voltage Rating And Type Per Characteristic: -1.5 volts power source and 5.5 volts power source **Time Rating Per Chacteristic:** 55.00 nanoseconds propagation delay time, low to high level output and 55.00 nanoseconds propagation delay time, high to low level Memory Device Type: **Memory Capacity:**

Test Data Document:

49956-848126 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

13 input

Solder

output

Rom

Unknown

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

NSN 5962-01-141-8099

Memory Microcircuit - Page 2 of 2

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